

INDUSTRIAL



ADATA Industrial & Embedded Solutions

M.2 SSD

ADATA IM2S3334 M.2 2242 solid state drives utilize 3D NAND flash, providing higher power efficiency and rugged reliability. Its read/write speed is up to 560/520MB per second. With support of LDPC ECC technology, SLC Caching and DRAM cache buffer, the IM2S3334 ensures data integrity and maintains high performance. All IM2S3334 models are compliant with JEDEC specifications and feature a low-power design intended for industrial applications which leverages ADATA proprietary A⁺ Testing Methodology. This ensures the drives meet the exacting requirements of industrial applications. For SSD quality, compatibility, and reliability, ADATA developed its own SSD validation process, covering functionality testing and reliability assurance. Furthermore, value-added ADATA SSD Toolbox software provides intuitive SSD management, S.M.A.R.T. data integrity, and system optimization, helping enhance industrial systems.

Key Features

- P/E cycle upgrade to 3K improved endurance and reliability
- 3D NAND Flash for higher capacity and durability
- Wide Temperature Support: -40°C to 85°C
- Supports LDPC ECC Technology
- Supports SLC Cache and DRAM Buffer
- Supports DEVSLP for power efficiency
- Supports S.M.A.R.T., NCQ and TRIM Command



Target Applications

Server. Data Center, Surveillance, Transportation, Notebooks, Desktops

ringer	RESISTO	Coating	•	Jaic	Resistant	(LTM)		Erase	•	Consumption
30μ Golden Finger	Anti-Sulfur Resistor		Wide Temperature	EDS & EMI Safe	Shock & Vibration	Lifetime Monitoring	Wear Leveling	Secure Erase	TRIM	Low Power Consumption

Specifications

Model	IM2S3334				
Interface	SATA III 6.0Gbps				
Form Factor	M.2 2242				
Dimensions (L x W x H)	42 x 22 x 3.5mm				
Flash Type	3D TLC				
Capacity	64GB – 512GB				
Sequential Read (Max.)	560MB/s				
Sequential Write (Max.)	520MB/s				
Operating Temperature (Commercial)	0°C to 70°C				
Operating Temperature (Industrial)	-40°C to 85°C				
Operating Voltage	3.3V				
Operating Humidity	5%-95% RH non-condensing				
Power Consumption (Max.)	2.4W				
MTBF (Est.)	>2,000,000 hours				
Shock Resistance	1500G/0.5ms, Half Sine Wave				
Vibration Resistance	20G (10-2000Hz)				
Technologies	DEVSLP, LDPC ECC, SLC Cache, DRAM Buffer, Wear Leveling				

Ordering Information

Capacity	Commercial	Industrial				
Capacity	(0°C to 70°C)	(-40°C to 85°C)				
64GB	IM2S3334-064GD	IM2S3334-064GP				
128GB	IM2S3334-128GD	IM2S3334-128GP				
256GB	IM2S3334-256GD	IM2S3334-256GP				
512GB	IM2S3334-512GD	IM2S3334-512GP				













Dimensions



